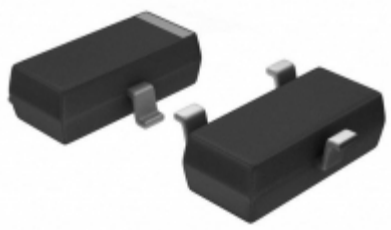








	<h2 style="color: red;">FJV4101RMTF</h2>
	<p>Hersteller-Teilenummer: FJV4101RMTF</p> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <p>Teil der Beschreibung: TRANS PREBIAS PNP 200MW SOT23-3</p> <p>Datenblätter: 1.FJV4101RMTF.pdf 2.FJV4101RMTF.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 18000 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FJV4101RMTF
Hersteller	Fairchild/ON Semiconductor
Beschreibung	TRANS PREBIAS PNP 200MW SOT23-3
Kategorie	Diskrete Halbleiterprodukte > Transistoren-Bipolar
Teilstatus	18000 pcs Stock
Serie	-
Befestigungsart	Surface Mount
Leistung - max	200mW
Verpackung / Gehäuse	TO-236-3, SC-59, SOT-23-3
Supplier Device-Gehäuse	SOT-23-3 (TO-236)
Transistor-Typ	PNP - Pre-Biased
Strom - Kollektor (Ic) (max)	100mA
Spannung - Kollektor-Emitter-Durchbruch (max)	50V
VCE Sättigung (Max) @ Ib, Ic	300mV @ 500µA, 10mA
Strom - Collector Cutoff (Max)	100nA (ICBO)
DC Stromgewinn (HFE) (Min) @ Ic, VCE	20 @ 10mA, 5V
Frequenz - Übergang	200MHz
Widerstand - Base (R1) (Ohm)	4.7k
Widerstand - Emitter-Basis (R2) (Ohm)	4.7k
Verpackung	Tape & Reel (TR)

FJV4101RMTF ist neu im Original, Suche FJV4101RMTF Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FJV4101RMTF Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FJV4101RMTF: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FJV4102RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3</p>	 <p>FJV4101RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3</p>	 <p>FJV4102RMTF Fairchild/ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3</p>	 <p>FJV3115RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>
 <p>FJV3115RMTF Fairchild/ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>	 <p>FJV4103RMTF Fairchild/ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3</p>	 <p>FJV3114RMTF Fairchild/ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>	 <p>FJV3113RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>

heiße Teile

Mehr

⚙ FJV3104RMTF	➔ FJV3105RMTF	➔ FJV3105RMTF	D FJV3106RMTF	➔ FJV3106RMTF
⊣ FJV3107RMTF	⚙ FJV3107RMTF	D FJV3108RMTF	➔ FJV3108RMTF	➔ FJV3109R
⚙ FJV3109RMTF	⊣ FJV3109RMTF	⚙ FJV3110RMTF	➔ FJV3110RMTF	➔ FJV3111RMTF
D FJV3111RMTF	⚙ FJV3112RMTF	⊣ FJV3112RMTF	⚙ FJV3113RMTF	➔ FJV3113RMTF
➔ FJV3114RMTF	➔ FJV3114RMTF	⚙ FJV3115RMTF	⊣ FJV3115RMTF	➔ FJV4101RMTF
➔ FJV4102RLIMTF	➔ FJV4102RMTF	D FJV4102RMTF	⚙ FJV4103RMTF	⊣ FJV4103RMTF
⚙ FJV4104RMTF	D FJV4104RMTF	➔ FJV4105RMTF	➔ FJV4105RMTF	➔ FJV4106RMTF
⊣ FJV4106RMTF	⚙ FJV4107RMTF	➔ FJV4107RMTF	➔ FJV4108RMTF	➔ FJV4108RMTF
⚙ FJV4109RMTF	⊣ FJV4109RMTF	⚙ FJV4110RMTF	D FJV4110RMTF	➔ FJV4111RMTF
➔ FJV4111RMTF	⚙ FJV4112RMTF	⊣ FJV4112RMTF	⚙ FJV4113RMTF	➔ FJV4113RMTF

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